



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



MAC997 Series

Preferred Device

Sensitive Gate Triacs

Silicon Bidirectional Thyristors

Designed for use in solid state relays, MPU interface, TTL logic and any other light industrial or consumer application. Supplied in an inexpensive TO-92 package which is readily adaptable for use in automatic insertion equipment.

- One-Piece, Injection-Molded Package
- Blocking Voltage to 600 Volts
- Sensitive Gate Triggering in Four Trigger Modes (Quadrants) for all possible Combinations of Trigger Sources, and especially for Circuits that Source Gate Drives
- All Diffused and Glassivated Junctions for Maximum Uniformity of Parameters and Reliability
- Improved Noise Immunity (dv/dt Minimum of 20 V/ μ sec at 110°C)
- Commutating di/dt of 1.6 Amps/msec at 110°C
- High Surge Current of 8 Amps
- Device Marking: Device Type, e.g., for MAC997A6: MAC7A6, Date Code
- **These devices are available in Pb-free package(s). Specifications herein apply to both standard and Pb-free devices. Please see our website at www.onsemi.com for specific Pb-free orderable part numbers, or contact your local ON Semiconductor sales office or representative.**

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

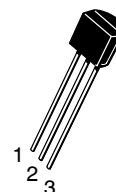
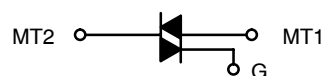
Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage ($T_J = -40$ to $+110^\circ\text{C}$) ⁽¹⁾ Sine Wave 50 to 60 Hz, Gate Open MAC997A6,B6 MAC997A8,B8	V_{DRM} , V_{RRM}	400 600	Volts
On-State RMS Current Full Cycle Sine Wave 50 to 60 Hz ($T_C = +50^\circ\text{C}$)	$I_{\text{T(RMS)}}$	0.8	Amp
Peak Non-Repetitive Surge Current One Full Cycle, Sine Wave 60 Hz ($T_C = 110^\circ\text{C}$)	I_{TSM}	8.0	Amps
Circuit Fusing Considerations ($t = 8.3$ ms)	I^2t	.26	A^2s
Peak Gate Voltage ($t \leq 2.0$ μs , $T_C = +80^\circ\text{C}$)	V_{GM}	5.0	Volts
Peak Gate Power ($t \leq 2.0$ μs , $T_C = +80^\circ\text{C}$)	P_{GM}	5.0	Watts
Average Gate Power ($T_C = 80^\circ\text{C}$, $t \leq 8.3$ ms)	$P_{\text{G(AV)}}$	0.1	Watt
Peak Gate Current ($t \leq 2.0$ μs , $T_C = +80^\circ\text{C}$)	I_{GM}	1.0	Amp
Operating Junction Temperature Range	T_J	-40 to +110	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-40 to +150	$^\circ\text{C}$



ON Semiconductor

<http://onsemi.com>

TRIACS
0.8 AMPERE RMS
400 thru 600 VOLTS



TO-92 (TO-226AA)
CASE 029
STYLE 12

PIN ASSIGNMENT	
1	Main Terminal 1
2	Gate
3	Main Terminal 2

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MAC997 Series

(1) V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

THEMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	75	$^{\circ}C/W$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^{\circ}C/W$
Maximum Lead Temperature for Soldering Purposes for 10 Seconds	T_L	260	$^{\circ}C$

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
----------------	--------	-----	-----	-----	------

OFF CHARACTERISTICS

Peak Repetitive Blocking Current ($V_D = \text{Rated } V_{DRM}, V_{RRM}; \text{ Gate Open}$)	I_{DRM}, I_{RRM}	—	—	10	μA
$T_J = 25^{\circ}C$		—	—	100	μA
$T_J = +110^{\circ}C$		—	—		

ON CHARACTERISTICS

Peak On-State Voltage ($I_{TM} = \pm .85 \text{ A Peak}; \text{ Pulse Width } \leq 2.0 \text{ ms}, \text{ Duty Cycle } \leq 2.0\%$)	V_{TM}	—	—	1.9	Volts
Gate Trigger Current (Continuous dc) ($V_D = 12 \text{ Vdc}, R_L = 100 \text{ Ohms}$)	I_{GT}				mA
MT2(+), G(+) MAC997A6,A8		—	—	5.0	
MT2(+), G(-)		—	—	5.0	
MT2(-), G(-)		—	—	5.0	
MT2(-), G(+)		—	—	7.0	
MT2(+), G(+) MAC997B6,B8		—	—	3.0	
MT2(+), G(-)		—	—	3.0	
MT2(-), G(-)		—	—	3.0	
MT2(-), G(+)		—	—	5.0	
Latching Current ($V_D = 12 \text{ V}, I_G = 10 \text{ mA}$)	I_L				mA
MT2(+), G(+) All Types		—	1.6	15	
MT2(+), G(-) All Types		—	10.5	20	
MT2(-), G(-) All Types		—	1.5	15	
MT2(-), G(+) All Types		—	2.5	15	
Gate Trigger Voltage (Continuous dc) ($V_D = 12 \text{ Vdc}, R_L = 100 \text{ Ohms}$)	V_{GT}				Volts
MT2(+), G(+) All Types		—	.66	2.0	
MT2(+), G(-) All Types		—	.77	2.0	
MT2(-), G(-) All Types		—	.84	2.0	
MT2(-), G(+) All Types		—	.88	2.5	
Gate Non-Trigger Voltage ($V_D = 12 \text{ V}, R_L = 100 \text{ Ohms}, T_J = 110^{\circ}C$) All Four Quadrants	V_{GD}	0.1	—	—	Volts
Holding Current ($V_D = 12 \text{ Vdc}, \text{ Initiating Current} = 200 \text{ mA}, \text{ Gate Open}$)	I_H	—	1.5	10	mA
Turn-On Time ($V_D = \text{Rated } V_{DRM}, I_{TM} = 1.0 \text{ A pk}, I_G = 25 \text{ mA}$)	t_{gt}	—	2.0	—	μs

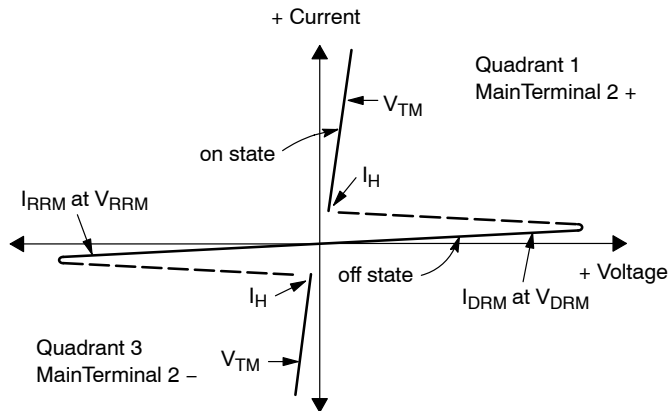
DYNAMIC CHARACTERISTICS

Rate of Change of Commutating Current ($V_D = 400 \text{ V}, I_{TM} = .84 \text{ A}, \text{ Commutating } dv/dt = 1.5 \text{ V}/\mu s, \text{ Gate Open}, T_J = 110^{\circ}C, f = 250 \text{ Hz}, \text{ with Snubber}$)	$di/dt(c)$	1.6	—	—	A/ms
Critical Rate of Rise of Off-State Voltage ($V_D = \text{Rated } V_{DRM}, \text{ Exponential Waveform}, \text{ Gate Open}, T_J = 110^{\circ}C$)	dv/dt	20	60	—	V/ μs
Repetitive Critical Rate of Rise of On-State Current Pulse Width = 20 μs , $IPK_{max} = 15 \text{ A}, diG/dt = 1 \text{ A}/\mu s, f = 60 \text{ Hz}$	di/dt	—	—	10	A/ μs

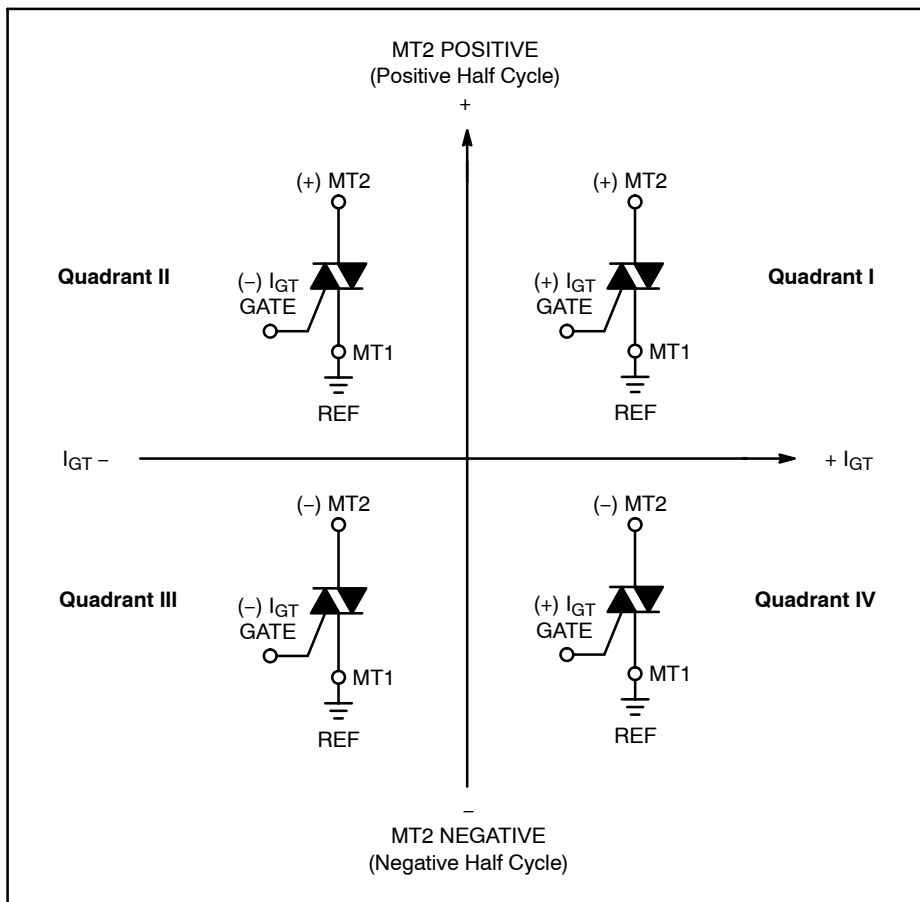
MAC997 Series

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Reverse Off State Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I_H	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1.
 With in-phase signals (using standard AC lines) quadrants I and III are used.

MAC997 Series

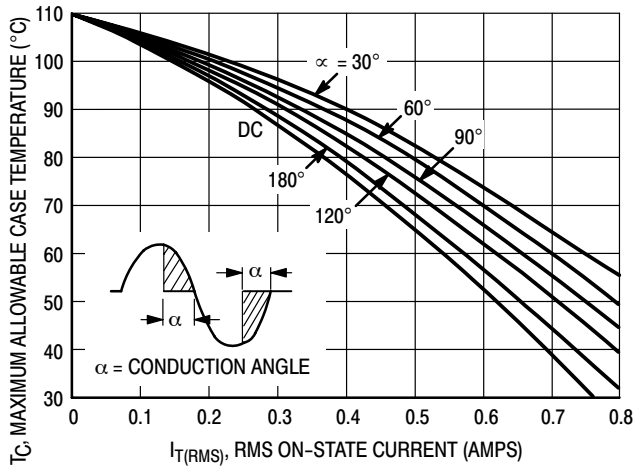


Figure 1. RMS Current Derating

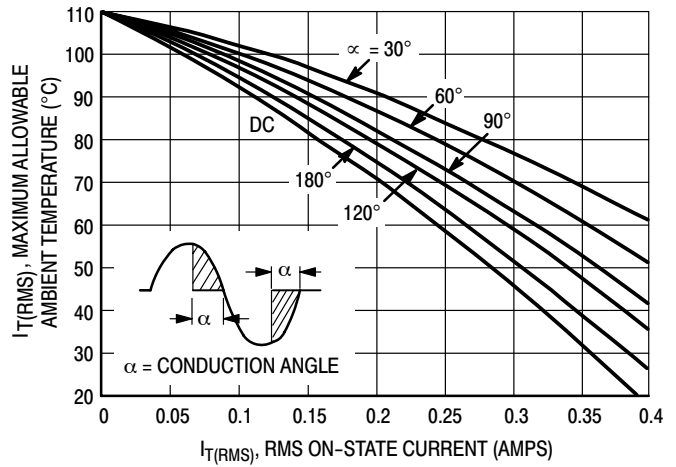


Figure 2. RMS Current Derating

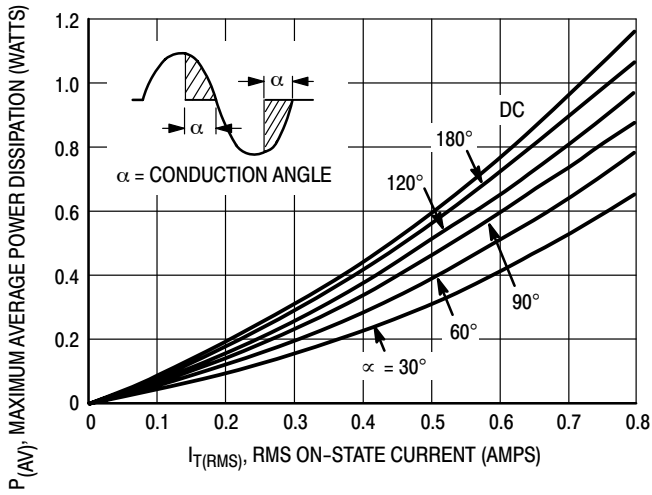


Figure 3. Power Dissipation

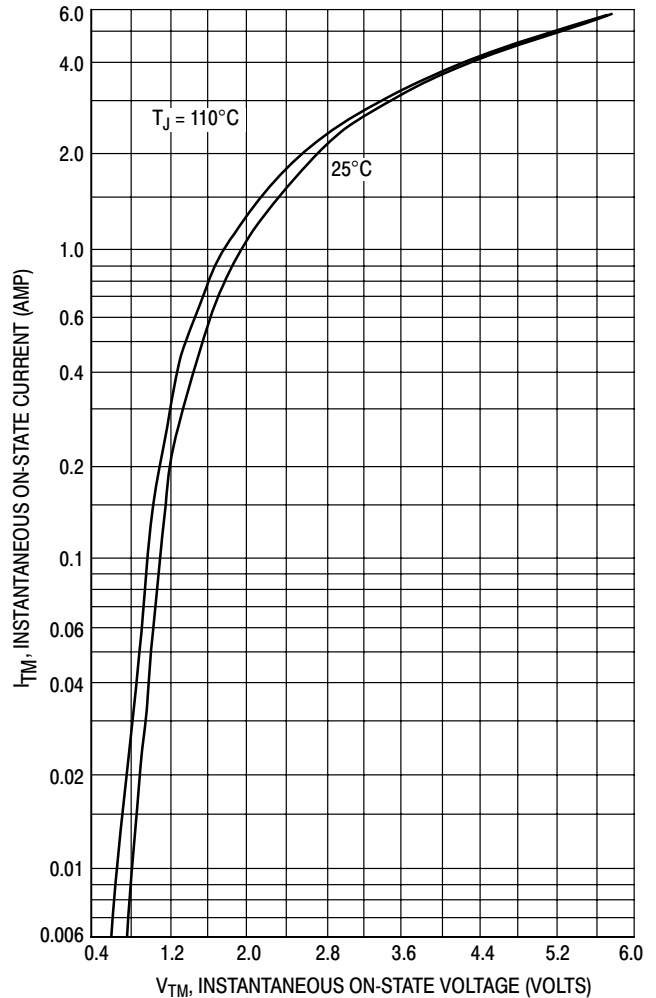


Figure 4. On-State Characteristics

MAC997 Series

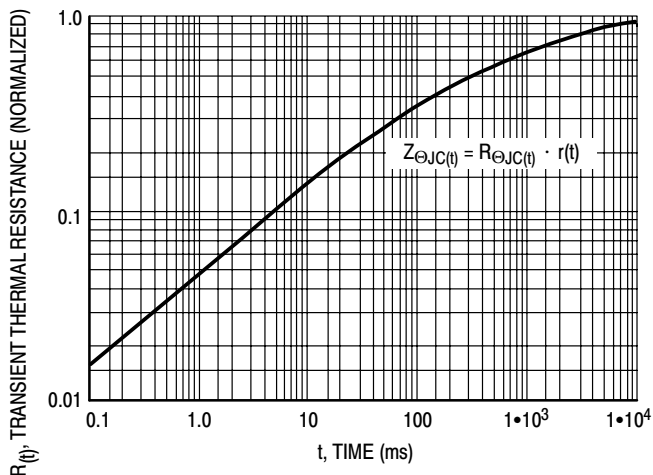


Figure 5. Transient Thermal Response

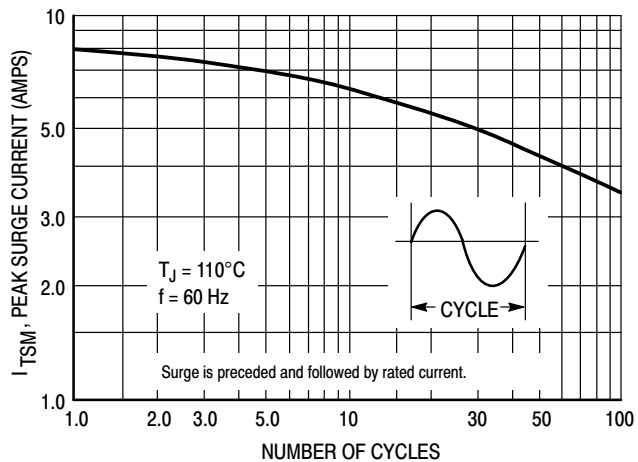


Figure 6. Maximum Allowable Surge Current

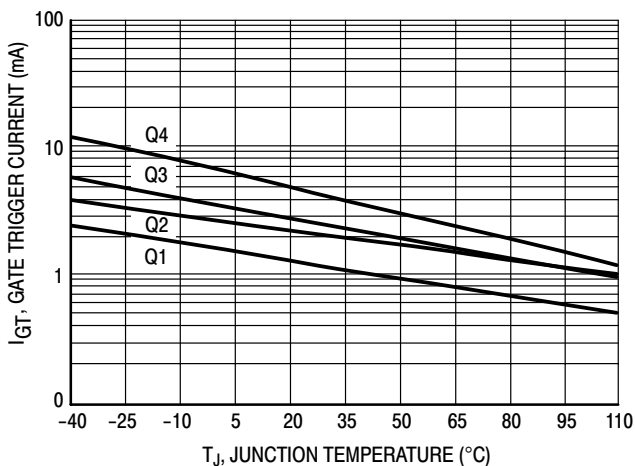


Figure 7. Typical Gate Trigger Current versus Junction Temperature

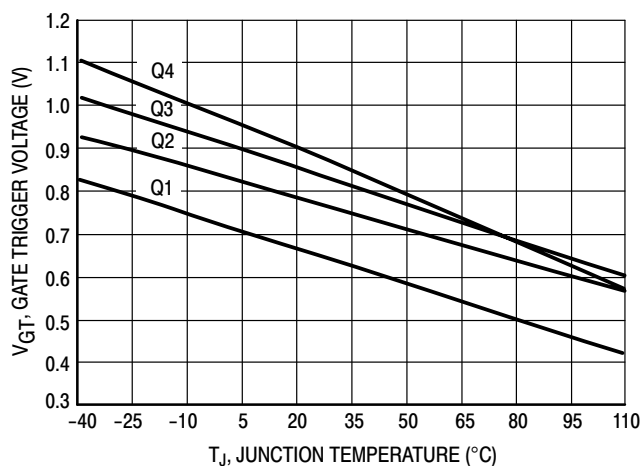


Figure 8. Typical Gate Trigger Voltage versus Junction Temperature

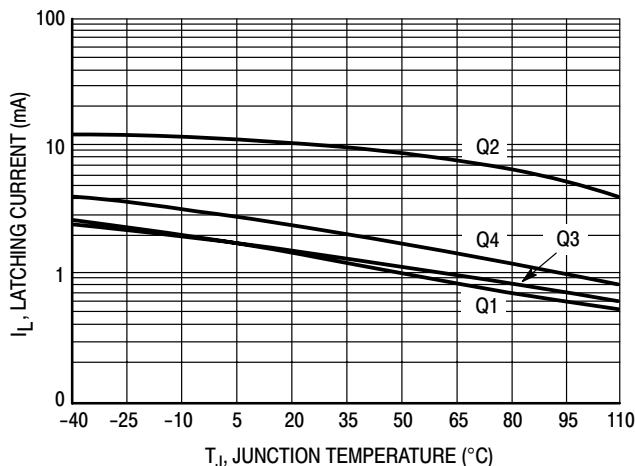


Figure 9. Typical Latching Current versus Junction Temperature

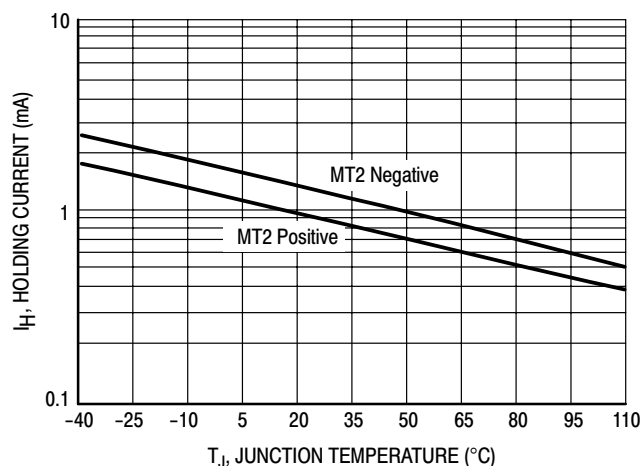
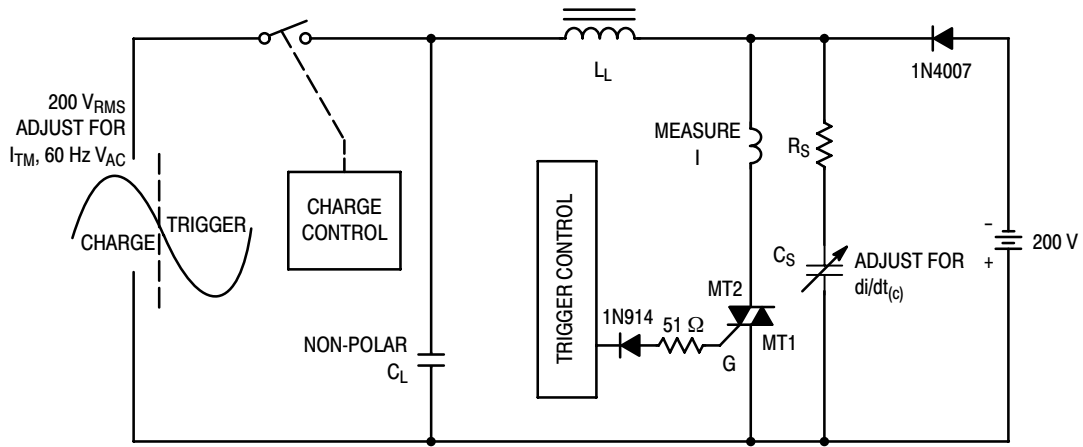


Figure 10. Typical Holding Current versus Junction Temperature

MAC997 Series



Note: Component values are for verification of rated $(di/dt)_c$. See AN1048 for additional information.

Figure 11. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current $(di/dt)_c$

MAC997 Series

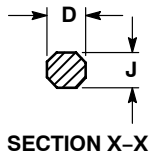
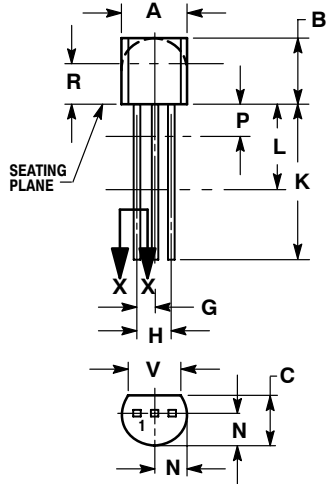
ORDERING & SHIPPING INFORMATION: MAC97 Series packaging options, Device Suffix

U.S.	Europe Equivalent	Shipping	Description of TO92 Tape Orientation
	MAC997A6RL1, A8RL1 MAC997B6RL1, B8RL1	Radial Tape and Reel (2K/Reel)	Flat side of TO92 and adhesive tape visible
MAC997A6,A8 MAC997B6,B8		Bulk in Box (5K/Box)	N/A, Bulk
MAC997A6RLRP, A8RLRP MAC997B6RLRP, B8RLRP		Radial Tape and Fan Fold Box (2K/Box)	Round side of TO92 and adhesive tape visible

MAC997 Series

PACKAGE DIMENSIONS

TO-92 (TO-226AA)
CASE 029-11
ISSUE AJ



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.


DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 12:

- PIN 1. MAIN TERMINAL 1
2. GATE
3. MAIN TERMINAL 2

Notes

Notes

ON Semiconductor and  are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
P.O. Box 61312, Phoenix, Arizona 85082-1312 USA

Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada

Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada

Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center
2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051
Phone: 81-3-5773-3850

ON Semiconductor Website: <http://onsemi.com>

Order Literature: <http://www.onsemi.com/litorder>

For additional information, please contact your
local Sales Representative.